TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSVII)

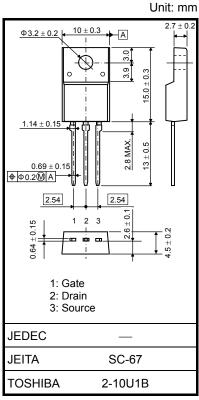
TK19A45D

Switching Regulator Applications

- Low drain-source ON-resistance: RDS (ON) = 0.19 Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 10 \text{ S (typ.)}$
- Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 450 \text{ V)}$
- Enhancement-mode: $V_{th} = 2.0 \text{ to } 4.0 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA)}$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	450	V	
Gate-source voltage		V_{GSS}	±30	V	
Drain current	DC (Note 1)	I _D	19		
	Pulse (t = 1 ms) (Note 1)	I _{DP}	76	Α	
Drain power dissipati	on (Tc = 25°C)	P _D	50	W	
Single pulse avalanche energy (Note 2)		E _{AS}	513	mJ	
Avalanche current		I _{AR}	19	Α	
Repetitive avalanche energy (Note 3)		E _{AR}	5.0	mJ	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



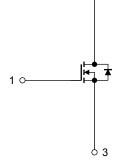
Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	2.5	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W

Internal Connection



Note 1: Please use devices on conditions that the channel temperature is below 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 2.37 mH, R_G = 25 Ω , I_{AR} = 19 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.

Start of commercial production 2009-08

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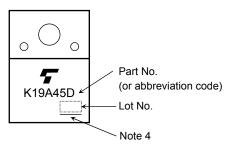
Electrical Characteristics (Ta = 25°C)

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm30~V,~V_{DS}=0~V$	_	_	±1	μА
Drain cut-off current		I _{DSS}	V _{DS} = 450 V, V _{GS} = 0 V	_	_	10	μА
Drain-source breakdown voltage		V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	450	_	_	V
Gate threshold vo	oltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2.0	_	4.0	V
Drain-source ON	-resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 9.5 A	_	0.19	0.25	Ω
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 9.5 A	2.4	10	_	S
Input capacitance		C _{iss}		_	2600	_	pF
Reverse transfer capacitance		C _{rss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	_	11	_	
Output capacitance		Coss		_	280	_	
Switching time	Rise time	t _r	10 V V_{GS} 0 V $V_{DD} \approx 200 \text{ V}$		50		. ns
	Turn-on time	t _{on}			100	_	
	Fall time	t _f			25		
	Turn-off time	t _{off}	Duty ≤ 1%, t _W = 10 μs	_	150	_	
Total gate charge		Qg		_	45	_	
Gate-source charge		Qgs	$V_{DD} \approx 360 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 19 \text{ A}$	_	28	_	nC
Gate-drain charge		Q _{gd}		_	17	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

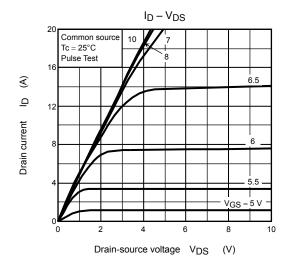
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	_	_	_	19	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	76	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 19 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	I _{DR} = 19 A, V _{GS} = 0 V,	_	1700		ns
Reverse recovery charge	Q _{rr}	dl _{DR} /dt = 100 A/μs	_	25	_	μС

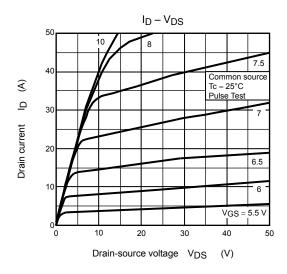
Marking

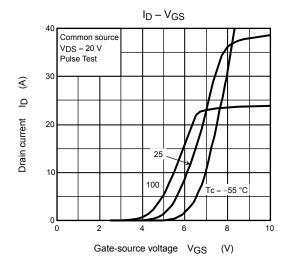


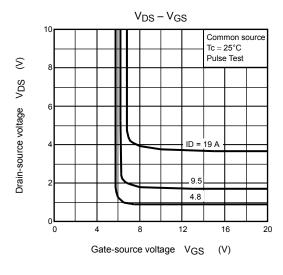
Note 4 : A line under a Lot No. identifies the indication of product Labels $\hbox{[[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]}$

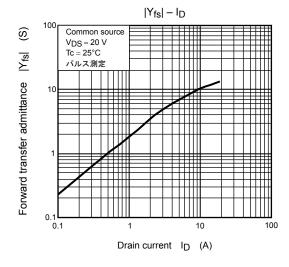
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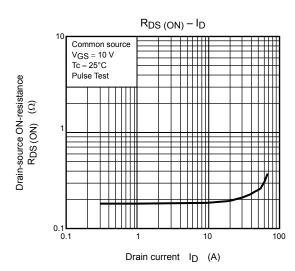


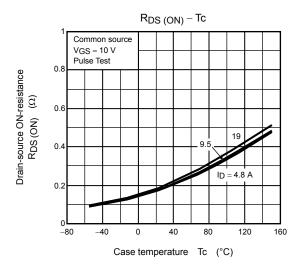


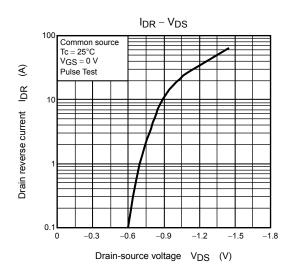


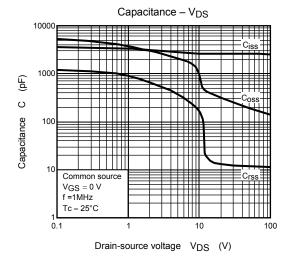


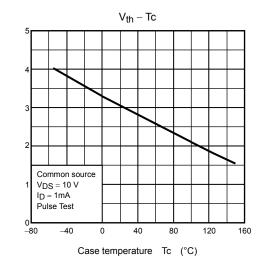


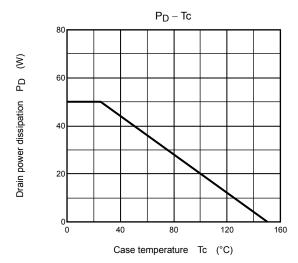


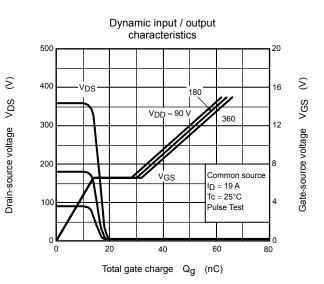








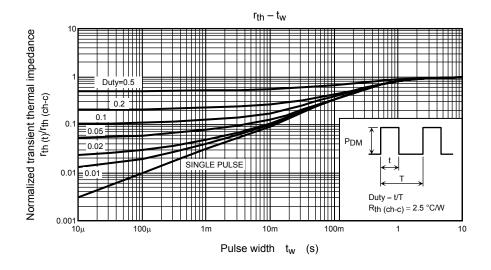


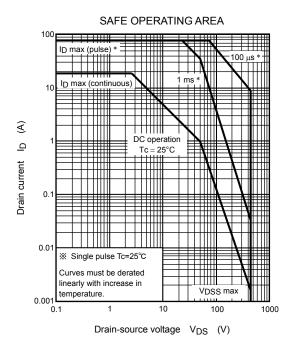


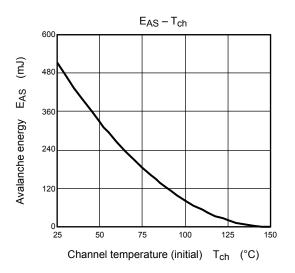
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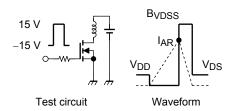
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Gate threshold voltage









$$R_G = 25~\Omega$$

$$V_{DD} = 90~V,~L = 2.37~mH$$

$$EAS = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BVDSS}{BVDSS - VDD} \right)$$

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